

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S107	11	((fin with (mosfet or misfet or igfet or fet or transistor)) or fin\$1fet) same fermi)	US-PGPUB; USPAT	OR	ON	2005/11/08 12:16
S105	9	S104 and (@ad<"20040319" or @rlad<"20040319")	US-PGPUB; USPAT	OR	ON	2005/11/08 12:16
S108	9	S107 and (@ad<"20040319" or @rlad<"20040319")	US-PGPUB; USPAT	OR	ON	2005/11/08 12:22
S113	41	S112 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thickness with (thick or thicker or higher or lower or greater or thinner or thin)))	US-PGPUB; USPAT	OR	ON	2005/11/08 12:24
S115	114	finfet	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 12:30
S118	0	S116 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)) with thickness)	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 12:31
S117	0	S116 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thickness near different))	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 12:31
S119	2	S116 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)))	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 12:32
S112	360	S111 and (@ad<"20040319" or @rlad<"20040319")	US-PGPUB; USPAT	OR	ON	2005/11/08 12:33
S111	421	finfet	US-PGPUB; USPAT	OR	ON	2005/11/08 12:33
S125	3	S124 not S114	US-PGPUB; USPAT	OR	ON	2005/11/08 12:34
S114	18	S112 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thickness near different))	US-PGPUB; USPAT	OR	ON	2005/11/08 12:34
S128	23	S127 and (@pd<"20040319")	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 12:42
S127	170	(finfet or fin\$1fet or (fin adj field adj effect))	EPO; JPO; DERWENT	OR	ON	2005/11/08 12:42
S126	3	S123 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thickness near (higher or lower)))	US-PGPUB; USPAT	OR	ON	2005/11/08 12:42

S11 6	15	S115 and (@pd<"20040319")	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 12:42
S12 9	0	S128 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thickness near (higher or lower or different)))	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/08 12:43
S13 2	19	S131 not S130	US-PGPUB; USPAT	OR	ON	2005/11/08 12:44
S13 1	29	S122 and (@ad<"20010319")	US-PGPUB; USPAT	OR	ON	2005/11/08 12:44
S13 0	10	S122 and (@ad<"20000319")	US-PGPUB; USPAT	OR	ON	2005/11/08 12:44
S12 2	478	(finfet or fin\$1fet or (fin adj field adj effect))	US-PGPUB; USPAT	OR	ON	2005/11/08 14:07
S13 7	0	S135 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thickness near2 different))	US-PGPUB; USPAT	OR	ON	2005/11/08 14:08
S13 6	0	S135 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thickness near different))	US-PGPUB; USPAT	OR	ON	2005/11/08 14:08
S12 3	398	S122 and (@ad<"20040319" or @rlad<"20040319")	US-PGPUB; USPAT	OR	ON	2005/11/08 14:08
S14 0	0	((multiple or plurality) adj (finfet or fin\$1fet or (fin adj field adj effect) or (fin adj type) or fin\$1type)) with voltage)	US-PGPUB; USPAT	OR	ON	2005/11/08 14:11
S13 9	0	((multiple or plurality) adj (finfet or fin\$1fet or (fin adj field adj effect) or (fin adj type) or fin\$1type)) with threshold)	US-PGPUB; USPAT	OR	ON	2005/11/08 14:11
S13 5	48	S134 and (@ad<"20040319" or @rlad<"20040319")	US-PGPUB; USPAT	OR	ON	2005/11/08 14:11
S14 3	5	((finfet or fin\$1fet or (fin adj field adj effect) or (fin adj type) or fin\$1type) with different with voltage)	US-PGPUB; USPAT	OR	ON	2005/11/08 14:12
S14 1	7	((multiple or plurality) adj (finfet or fin\$1fet or (fin adj field adj effect) or (fin adj type) or fin\$1type)) with different)	US-PGPUB; USPAT	OR	ON	2005/11/08 14:12
S14 2	7	S141 and (@ad<"20040319" or @rlad<"20040319")	US-PGPUB; USPAT	OR	ON	2005/11/08 14:13
S14 6	5	((finfet or fin\$1fet or (fin adj field adj effect) or (fin adj type) or fin\$1type) with different with thicknesses)	US-PGPUB; USPAT	OR	ON	2005/11/08 14:14

S14 5	4	S144 and (@ad<"20040319" or @rlad<"20040319")	US-PGPUB; USPAT	OR	ON	2005/11/08 14:14
S14 4	5	((finfet or fin\$1fet or (fin adj field adj effect) or (fin adj type) or fin\$1type) with different with voltage)	US-PGPUB; USPAT	OR	ON	2005/11/08 14:14
S13 4	49	((multiple or plurality) adj (finfet or fin\$1fet or (fin adj field adj effect) or (fin adj type) or fin\$1type))	US-PGPUB; USPAT	OR	ON	2005/11/08 14:16
S15 0	0	((several) adj (finfet or fin\$1fet or (fin adj field adj effect) or (fin adj type) or fin\$1type) with ("same" adj (chip or substrate or surface or wafer)))	US-PGPUB; USPAT	OR	ON	2005/11/08 14:17
S14 8	4	((multiple or plurality) adj (finfet or fin\$1fet or (fin adj field adj effect) or (fin adj type) or fin\$1type) with ("same" adj (chip or substrate or surface or wafer)))	US-PGPUB; USPAT	OR	ON	2005/11/08 14:17
S14 7	4	S146 and (@ad<"20040319" or @rlad<"20040319")	US-PGPUB; USPAT	OR	ON	2005/11/08 14:17
S15 4	7	S153 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thickness or thick or thicker or thinner))	US-PGPUB; USPAT	OR	ON	2005/11/08 14:18
S15 3	13	S152 not S149	US-PGPUB; USPAT	OR	ON	2005/11/08 14:18
S15 1	17	((finfet or fin\$1fet or (fin adj field adj effect) or (fin adj type) or fin\$1type) with ("same" adj (chip or substrate or surface or wafer)))	US-PGPUB; USPAT	OR	ON	2005/11/08 14:18
S14 9	4	S148 and (@ad<"20040319" or @rlad<"20040319")	US-PGPUB; USPAT	OR	ON	2005/11/08 14:18
S13 8	4	S135 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thickness or thick or thicker or thinner))	US-PGPUB; USPAT	OR	ON	2005/11/08 14:18
S12 4	21	S123 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thickness near different))	US-PGPUB; USPAT	OR	ON	2005/11/08 14:23
S15 8	0	((fin near "each") with (gate adj (oxide or dielectric or insulator or insulating or insulation)))	US-PGPUB; USPAT	OR	ON	2005/11/08 14:24
S15 7	0	((fin near "each") with (gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thick or thin or thickness))	US-PGPUB; USPAT	OR	ON	2005/11/08 14:24

S15 6	0	((fin near "each") with (gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thickness with different))	US-PGPUB; USPAT	OR	ON	2005/11/08 14:24
S16 2	2	"6921982"	US-PGPUB; USPAT	OR	ON	2005/11/11 12:23
S16 6	18	S165 not S161	US-PGPUB; USPAT	OR	ON	2005/11/11 12:37
S16 4	30	("20030151077" "20030178670" "20040174734" "20040219722" "20050017377" "20050023619" "20050029583" "20050051812" "6391695" "6433609" "6888199")	US-PGPUB; USPAT	OR	ON	2005/11/11 12:37
S16 1	11	("20030151077" "20030178670" "20040174734" "20040219722" "20050017377" "20050023619" "20050029583" "20050051812" "6391695" "6433609" "6888199").PN.	US-PGPUB; USPAT	OR	ON	2005/11/11 12:37
S15 2	17	S151 and (@ad<"20040319" or @rlad<"20040319")	US-PGPUB; USPAT	OR	ON	2005/11/11 12:37
S16 3	10	S161 and (dual\$1gated or double\$1gated or two\$1gated or twin\$1gated or ((dual or double or two or twin) adj (gate or gated or electrode)) or dual\$1gate or double\$1gate or two\$1gate or twin\$1gate or dual\$1electrode or double\$1electrode or two\$1electrode or twin\$1electrode)	US-PGPUB; USPAT	OR	ON	2005/11/11 12:38
S15 5	0	((fin near "each") with (gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thickness near different))	US-PGPUB; USPAT	OR	ON	2005/11/11 12:39
S17 1	0	S170 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)) with thickness)	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/11 13:01
S17 0	7	S169 and (@pd<"20040319")	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/11 13:01

S16 9	37	(fin\$1fet or (fin adj fet) or (fin adj field adj effect) or (fin adj type) or fin\$1type) and (dual\$1gated or double\$1gated or two\$1gated or twin\$1gated or ((dual or double or two or twin) adj (gate or gated or electrode)) or dual\$1gate or double\$1gate or two\$1gate or twin\$1gate or dual\$1electrode or double\$1electrode or two\$1electrode or twin\$1electrode) and (@ad<"20040319" or @rlad<"20040319")	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/11 13:01
S16 8	20	S167 and ((gate adj (oxide or dielectric or insulator or insulating or insulation)) with (thickness near different))	US-PGPUB; USPAT	OR	ON	2005/11/11 13:01
S16 7	394	(fin\$1fet or (fin adj fet) or (fin adj field adj effect) or (fin adj type) or fin\$1type) and (dual\$1gated or double\$1gated or two\$1gated or twin\$1gated or ((dual or double or two or twin) adj (gate or gated or electrode)) or dual\$1gate or double\$1gate or two\$1gate or twin\$1gate or dual\$1electrode or double\$1electrode or two\$1electrode or twin\$1electrode) and (@ad<"20040319" or @rlad<"20040319")	US-PGPUB; USPAT	OR	ON	2005/11/11 13:01
S16 5	28	S164 and (@ad<"20040319" or @rlad<"20040319")	US-PGPUB; USPAT	OR	ON	2005/11/11 13:01